BGU7031

1 GHz wideband low-noise amplifier Rev. 2 — 7 September 2010

Product data sheet

1. **Product profile**

1.1 General description

The BGU7031 MMIC is a wideband amplifier with internal biasing. It is designed specifically for high linearity, low-noise applications over a frequency range of 40 MHz to 1 GHz. It is especially suited to Set-Top Box applications.

The LNA is housed in a 6-pin SOT363 plastic SMD package.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Internally biased
- Flat gain between 40 MHz and 1 GHz
- Noise figure of 4.5 dB
- High linearity with an IP3_O of 29 dBm
- 75 Ω input and output impedance
- ESD protection > 2 kV Human Body Model (HBM) on all pins

1.3 Applications

- Terrestrial and cable Set-Top Boxes (STB)
- Silicon and "Can" tuners
- Personal and Digital Video Recorders (PVR and DVR)
- Home networking and in-house signal distribution



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1.4 Quick reference data

Table 1. Quick reference data

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_{S} = Z_{L} = 75 Ω ; R_{bias} = 43 Ω ; 40 MHz \leq f_{1} \leq 1000 MHz.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CC}	supply voltage	RF input AC coupled		4.75	5.0	5.25	V
I _{CC(tot)}	total supply current		[1]	-	43	-	mΑ
T_{amb}	ambient temperature			-10	+25	+70	°C
NF	noise figure			-	4.5	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	1 GHz		-	13	-	dBm
IP3 _O	output third-order intercept point		[2]	-	29	-	dBm

^[1] $I_{CC(tot)}$ is configurable with external resistor.

2. Pinning information

Table 2. Pinning

IUDIC Z.	i iiiiiiig		
Pin	Description	Simplified outline	Graphic symbol
1	RF_OUT		0.0
2	V _{CC}	6 5 4	$\begin{pmatrix} 3 & 2 \\ 1 & 1 \end{pmatrix}$
3	n.c.		6—
4	n.c.		
5	GND	□1 □2 □3	5 4 sym141
6	RF_IN		,

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BGU7031	-	plastic surface-mounted package; 6 leads	SOT363

4. Marking

Table 4. Marking codes

Type number	Marking code
BGU7031	SC%

Note: % character indicates the location of production.

^[2] The fundamental frequency (f_1) lies between 40 MHz and 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage	RF input AC coupled		-0.6	5.25	V
I _{CC(tot)}	total supply current	configurable with external resistor		-	60	mA
P _{tot}	total power dissipation	T _{sp} ≤ 100 °C	[1]	-	250	mW
Pi	input power	single tone		-	10	dBm
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-10	+70	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E		2	-	kV

^[1] T_{sp} is the temperature at the solder point of the ground lead.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		240	K/W

7. Characteristics

Table 7. Characteristics

 T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_{S} = Z_{L} = 75 \varOmega ; R_{bias} = 43 \varOmega ; 40 MHz \leq f_{1} \leq 1000 MHz.

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage	RF input AC coupled	4.75	5.0	5.25	V
I _{CC(tot)}	total supply current		-	43	-	mA
$ s_{21} ^2$	insertion power gain		-	10		dB
SL _{sl}	slope straight line		-	-1	-	dB
FL	flatness of frequency response		-	-0.2	-	dB
NF	noise figure		-	4.5	-	dB
RLin	input return loss		-	18	-	dB
RL _{out}	output return loss		-	12	-	dB
P _{L(1dB)}	output power at 1 dB gain compression	1 GHz	-	14	-	dBm
IP3 _O	output third-order intercept point	<u> </u>	<u>1]</u> _	29	-	dBm

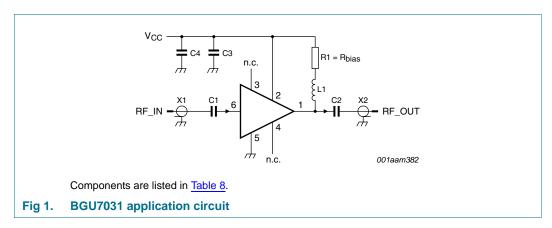
^[1] The fundamental frequency (f_1) lies between 40 MHz and 1000 MHz. The intermodulation product (IM3) is $2 \times f_2 - f_1$, where $f_2 = f_1 \pm 1$ MHz. Input power $P_i = -10$ dBm.

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8. Application information

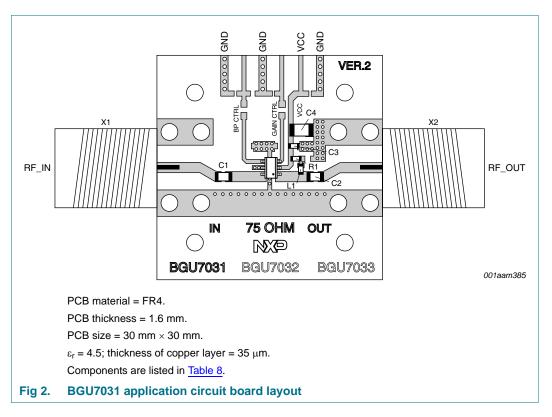
Other applications are possible. Please contact your local sales representative for more information. Application notes are available on the NXP website.

8.1 Application circuit



All control and supply lines must be decoupled properly. The decoupling capacitors must be placed as close to the device as possible.

8.2 Application circuit board layout



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Table 8. List of components See Figure 1 and Figure 2.

Description	Value	Remarks	Function
capacitor	10 nF		DC blocking
capacitor	10 nF		decoupling
capacitor	10 μF		decoupling
chip ferrite bead	$1.5~\mathrm{k}\Omega$	Murata BLM18HE152SN1DF	RF choke
resistor	43 Ω	[1] R _{bias}	bias setting
connector	75 Ω	F-connector, edge mount PCB reflow type, Bomar 861V509ERG	input/output
	capacitor capacitor capacitor chip ferrite bead resistor	capacitor 10 nF capacitor 10 μF capacitor 10 μF chip ferrite bead 1.5 kΩ resistor 43 Ω	capacitor 10 nF capacitor 10 nF capacitor 10 μ F capacitor 10 μ F chip ferrite bead 1.5 k Ω [1] Murata BLM18HE152SN1DF resistor 43 Ω [1] R_{bias} connector 75 Ω F-connector, edge mount PCB

^[1] L1 and R1 must have a power rating of 0.1 W or higher.

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9. Package outline

Plastic surface-mounted package; 6 leads

SOT363

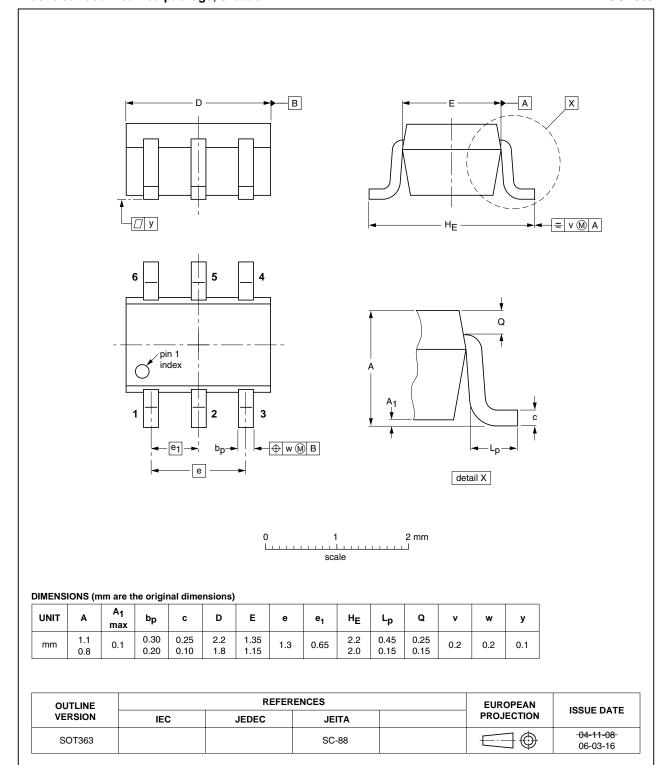


Fig 3. Package outline SOT363

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10. Abbreviations

Table 9. Abbreviations

Acronym	Description
AC	Alternating Current
DC	Direct Current
LNA	Low-Noise Amplifier
MMIC	Monolithic Microwave Integrated Circuit
PCB	Printed-Circuit Board
RF	Radio Frequency
SMD	Surface-Mounted Device

11. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGU7031 v.2	20100907	Product data sheet	-	BGU7031 v.1
Modifications:	The status	of this data sheet has been o	changed to Product dat	a sheet.
	• Table 5 on	page 3: The minimum value	for V _{CC} has been adde	d.
BGU7031 v.1	20100812	Preliminary data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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